



10-FZ074PA030SM-L623F08
10-PZ074PA030SM-L623F08Y
datasheet

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fastPACK 0 H C		650 V / 30 A
Features		
	<ul style="list-style-type: none">• High speed H-Bridge• High efficiency IGBT H5• Full current fast FWD• Integrated capacitors• Thermistor	
Target applications		flow 0 housing
	<ul style="list-style-type: none">• Power Supply• Solar Inverters• UPS• Welding & Cutting	
Types		Schematic
	<ul style="list-style-type: none">• 10-FZ074PA030SM-L623F08• 10-PZ074PA030SM-L623F08Y	

Maximum Ratings

$T_j = 25^\circ\text{C}$, unless otherwise specified

Parameter	Symbol	Condition	Value	Unit
H-Bridge Switch				
Collector-emitter voltage	V_{CES}		650	V
Collector current	I_C	$T_j = T_{jmax}$ $T_s = 80^\circ\text{C}$	31	A
Repetitive peak collector current	I_{CRM}	t_p limited by T_{jmax}	90	A
Total power dissipation	P_{tot}	$T_j = T_{jmax}$ $T_s = 80^\circ\text{C}$	60	W
Gate-emitter voltage	V_{GES}		± 20	V
Maximum Junction Temperature	T_{jmax}		175	$^\circ\text{C}$



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Maximum Ratings

$T_j = 25 \text{ }^\circ\text{C}$, unless otherwise specified

Parameter	Symbol	Condition	Value	Unit
H-Bridge Diode				
Peak Repetitive Reverse Voltage	V_{RRM}		650	V
Continuous (direct) forward current	I_F	$T_j = T_{jmax}$ $T_s = 80 \text{ }^\circ\text{C}$	33	A
Repetitive peak forward current	I_{FRM}		60	A
Total power dissipation	P_{tot}	$T_j = T_{jmax}$ $T_s = 80 \text{ }^\circ\text{C}$	50	W
Maximum Junction Temperature	T_{jmax}		175	$^\circ\text{C}$

Capacitor (DC)

Maximum DC voltage	V_{MAX}		630	V
Operation Temperature	T_{op}		-55...+125	$^\circ\text{C}$

Module Properties

Thermal Properties

Storage temperature	T_{stg}		-40...+125	$^\circ\text{C}$
Operation temperature under switching condition	T_{op}		-40...($T_{jmax} - 25$)	$^\circ\text{C}$

Isolation Properties

Isolation voltage	V_{isol}	DC Test Voltage* $t_p = 2 \text{ s}$	6000	V
		AC Voltage $t_p = 1 \text{ min}$	2500	V
Creepage distance			min. 12,7	mm
Clearance		with solder pins / with press-fit pins	9,55 / 9,57	mm
Comparative Tracking Index	CTI		> 200	

*100 % tested in production



Characteristic Values

Parameter	Symbol	Conditions						Value			Unit	
		V_{GE} [V]	V_{CE} [V]	I_c [A]	I_D [A]	T_j [°C]	V_{GS} [V]	V_{DS} [V]	I_F [A]	Min	Typ	Max

H-Bridge Switch

Static

Gate-emitter threshold voltage	$V_{GE(th)}$	$V_{GE} = V_{CE}$			0,0003	25	3,3	4	4,7	V
Collector-emitter saturation voltage	V_{CESat}		15		30	25 125 150		1,67 1,80 1,84	2,22	V
Collector-emitter cut-off current	I_{CES}		0	650		25			40	µA
Gate-emitter leakage current	I_{GES}		20	0		25			120	nA
Internal gate resistance	R_g							none		Ω
Input capacitance	C_{ies}	$f = 1\text{MHz}$	0	25	25			2100		pF
Reverse transfer capacitance	C_{res}							7,7		
Gate charge	Q_g		15	520	30	25		70		nC

Thermal

Thermal resistance junction to sink	$R_{th(j-s)}$	$\lambda_{paste} = 3,4 \text{ W/mK}$ (PSX)						1,57		K/W
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Dynamic

Turn-on delay time	$t_{d(on)}$	$R_{goff} = 16 \Omega$ $R_{gon} = 16 \Omega$	± 15	350	30	25		67		ns
Rise time	t_r					125		72		
						150		68		
Turn-off delay time	$t_{d(off)}$					25		8		
						125		9		
Fall time	t_f					150		10		
Turn-on energy (per pulse)	E_{on}	$Q_{rFWD} = 1,1 \mu\text{C}$ $Q_{rfwd} = 1,9 \mu\text{C}$ $Q_{rfwd} = 2,3 \mu\text{C}$				25		71		mWs
						125		83		
						150		88		
Turn-off energy (per pulse)	E_{off}					25		6		
						125		7		
						150		8		
						25		0,575		
						125		0,645		
						150		0,742		
						25		0,117		
						125		0,280		
						150		0,267		



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Characteristic Values

Parameter	Symbol	Conditions						Value			Unit
			V_{GE} [V] V_{GS} [V]	V_{CE} [V] V_{DS} [V] V_F [V]	I_c [A] I_D [A] I_F [A]	T_j [°C]	Min	Typ	Max		

H-Bridge Diode

Static

Forward voltage	V_F				30	25 125 150		1,52 1,46 1,44	1,92		V
Reverse leakage current	I_r			650		25			1,6		µA

Thermal

Thermal resistance junction to sink	$R_{th(j-s)}$	$\lambda_{paste} = 3,4 \text{ W/mK}$ (PSX)						1,92		K/W
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Dynamic

Peak recovery current	I_{RRM}	$di/dt = 3056 \text{ A/µs}$ $di/dt = 2584 \text{ A/µs}$ $di/dt = 2520 \text{ A/µs}$	± 15	350	30	25 125 150		18 28 31		A
Reverse recovery time	t_{rr}					25 125 150		92 115 125		ns
Recovered charge	Q_r					25 125 150		1,09 1,94 2,27		µC
Reverse recovered energy	E_{rec}					25 125 150		0,204 0,435 0,485		mWs
Peak rate of fall of recovery current	$(di_{rf}/dt)_{max}$					25 125 150		619 311 272		A/µs

Capacitor (DC)

Capacitance	C							150		nF
Tolerance							-10		+10	%
Dissipation factor		$f = 1 \text{ kHz}$				25			2,5	%

Thermistor

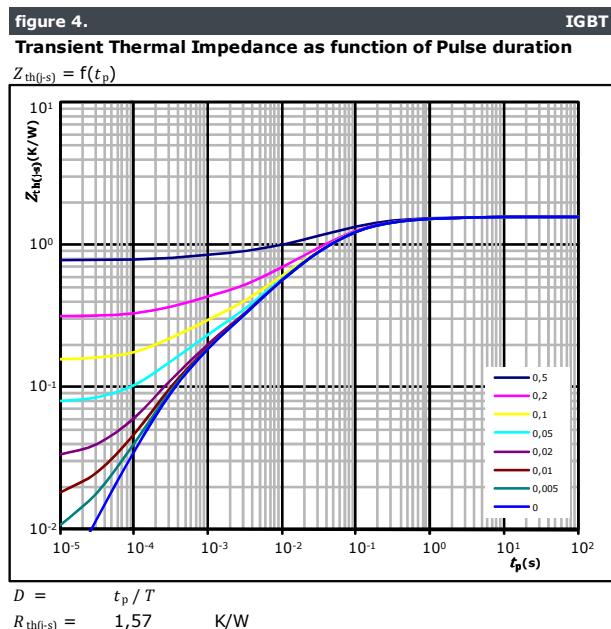
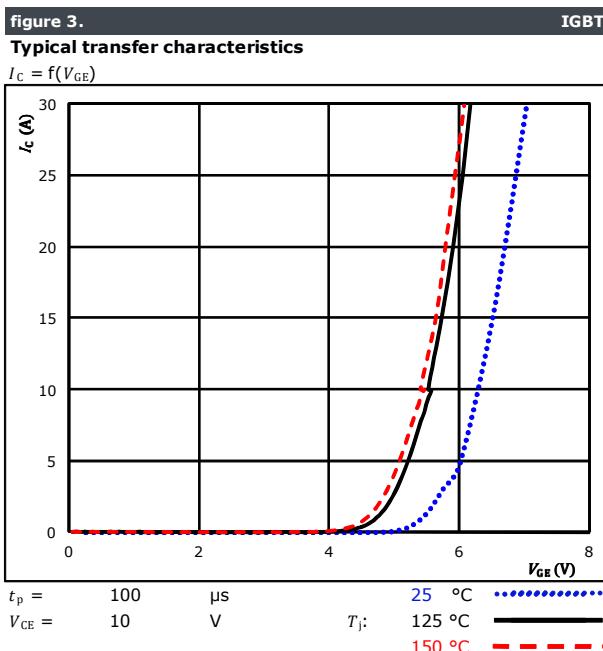
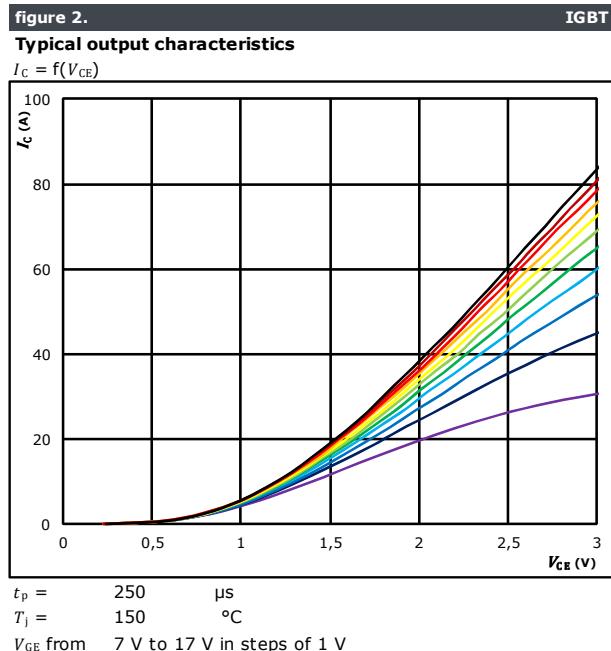
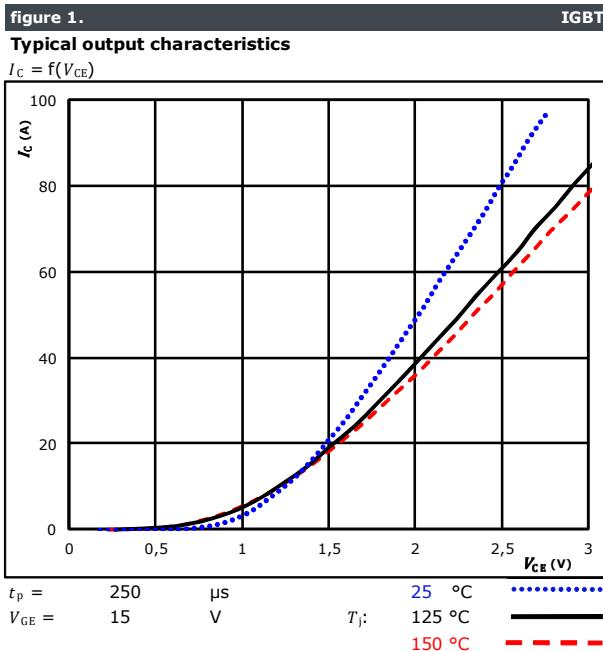
Rated resistance	R					25		22		kΩ
Deviation of R_{100}	$\Delta R/R$	$R_{100} = 1484 \Omega$				100	-5		5	%
Power dissipation	P					25		5		mW
Power dissipation constant						25		1,5		mW/K
B-value	$B_{(25/50)}$	Tol. ± 1 %				25		3962		K
B-value	$B_{(25/100)}$	Tol. ± 1 %				25		4000		K
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H-Bridge Switch Characteristics

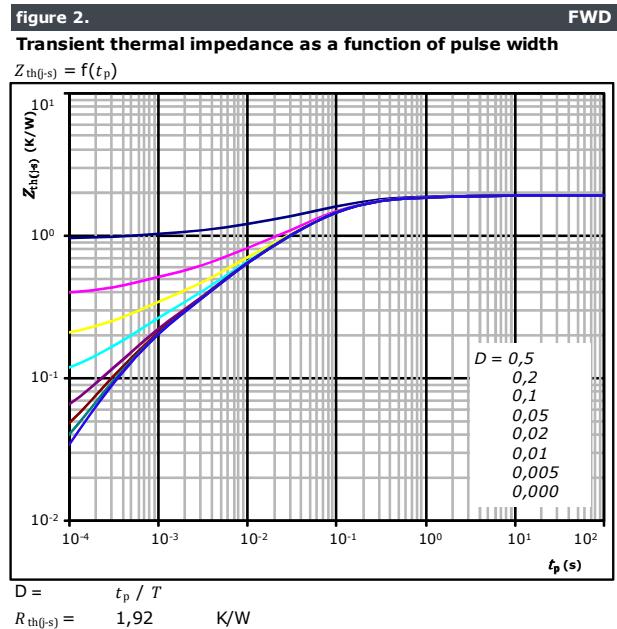
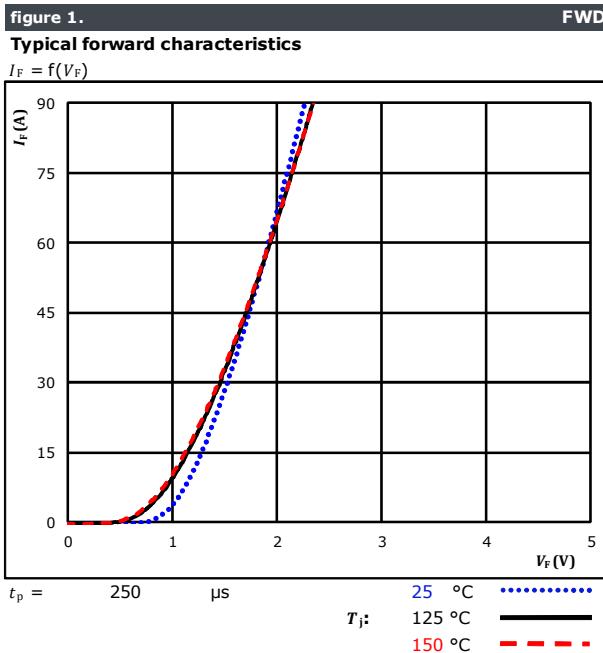




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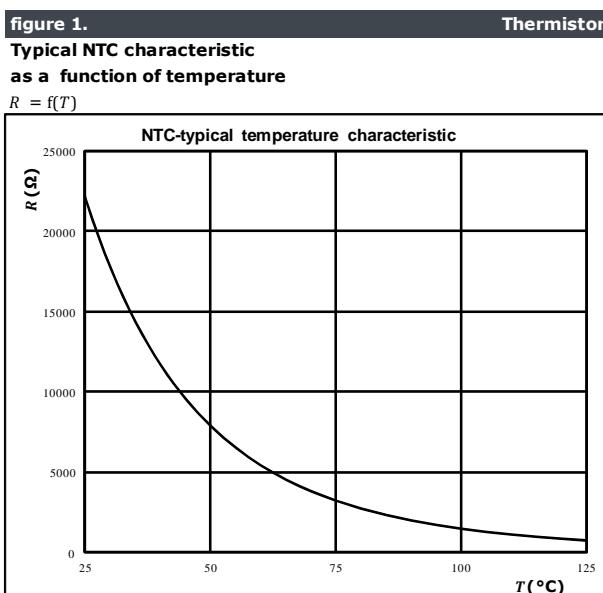
H-Bridge Diode Characteristics



FWD thermal model values

R (K/W)	τ (s)
9,41E-02	2,25E+00
3,44E-01	2,12E-01
8,56E-01	5,84E-02
3,61E-01	9,83E-03
1,37E-01	2,89E-03
1,27E-01	4,79E-04

Thermistor Characteristics





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H-Bridge Switching Characteristics

figure 1.

Typical switching energy losses as a function of collector current

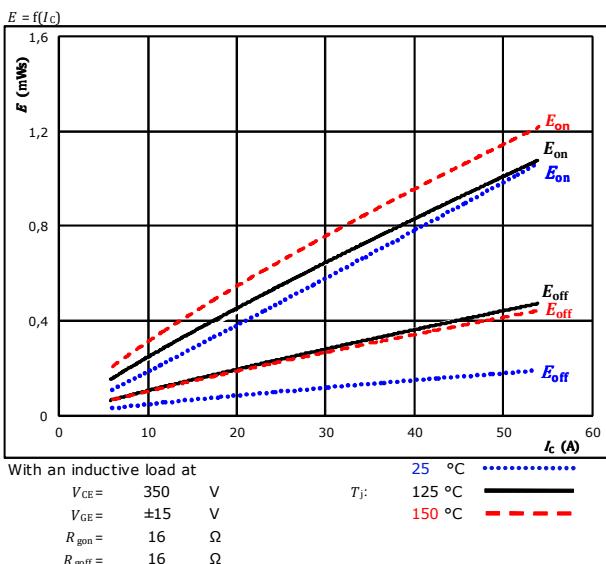


figure 2.

Typical switching energy losses as a function of gate resistor

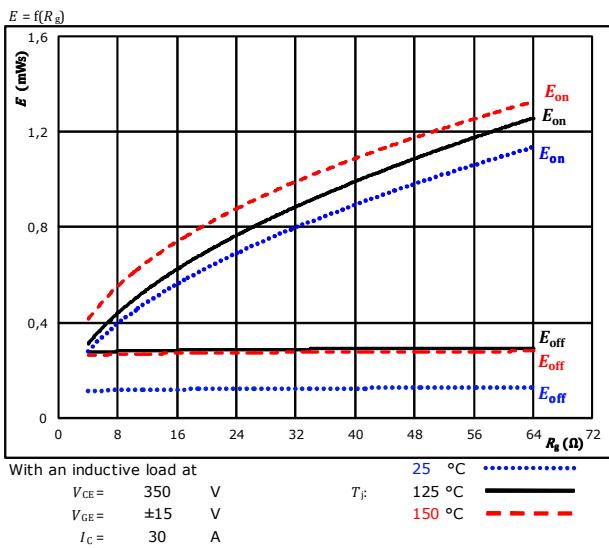


figure 3.

Typical reverse recovered energy loss as a function of collector current

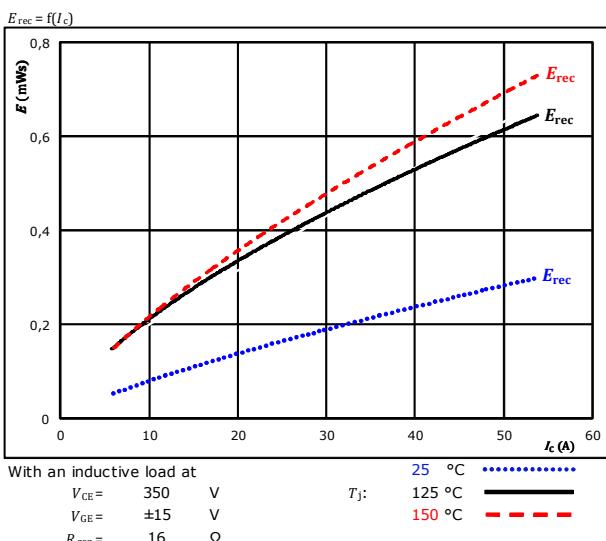
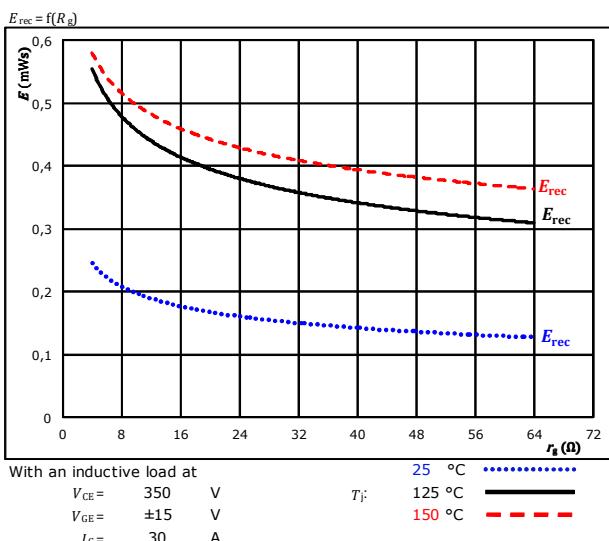


figure 4.

Typical reverse recovered energy loss as a function of gate resistor





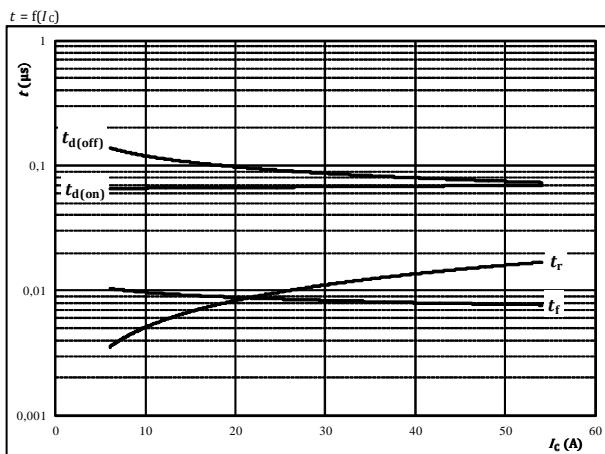
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H-Bridge Switching Characteristics

figure 5. IGBT

Typical switching times as a function of collector current

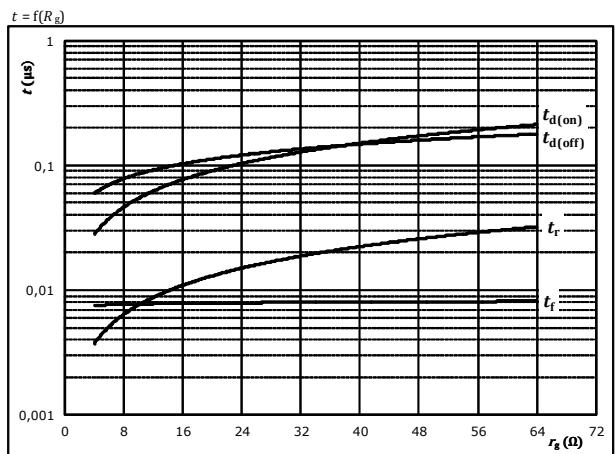


With an inductive load at

$T_J =$	150	°C
$V_{CE} =$	350	V
$V_{GE} =$	±15	V
$R_{gon} =$	16	Ω
$R_{goff} =$	16	Ω

figure 6. IGBT

Typical switching times as a function of gate resistor

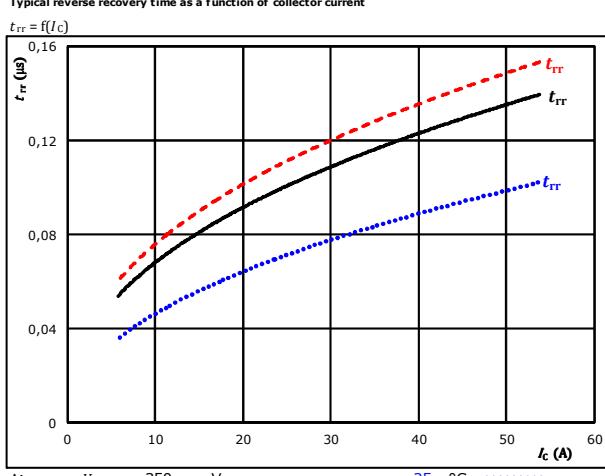


With an inductive load at

$T_J =$	150	°C
$V_{CE} =$	350	V
$V_{GE} =$	±15	V
$I_C =$	30	A

figure 7. FWD

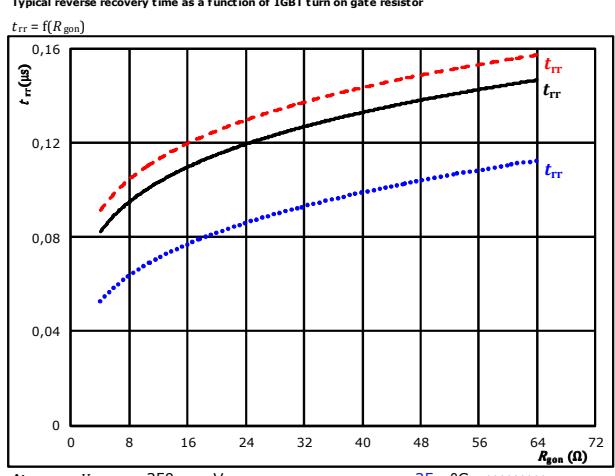
Typical reverse recovery time as a function of collector current



At	$V_{CE} =$	350	V	25	°C	-----
	$V_{GE} =$	±15	V	$T_J =$	125 °C	---
	$R_{gon} =$	16	Ω		150 °C	- - -

figure 8. FWD

Typical reverse recovery time as a function of IGBT turn on gate resistor



At	$V_{CE} =$	350	V	25	°C	-----
	$V_{GE} =$	±15	V	$T_J =$	125 °C	---
	$I_C =$	30	A		150 °C	- - -



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H-Bridge Switching Characteristics

figure 9.

Typical recovered charge as a function of collector current

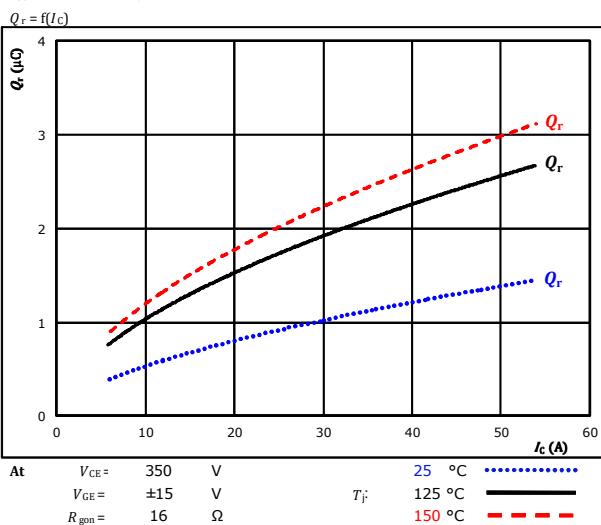


figure 10.

Typical recovered charge as a function of IGBT turn on gate resistor

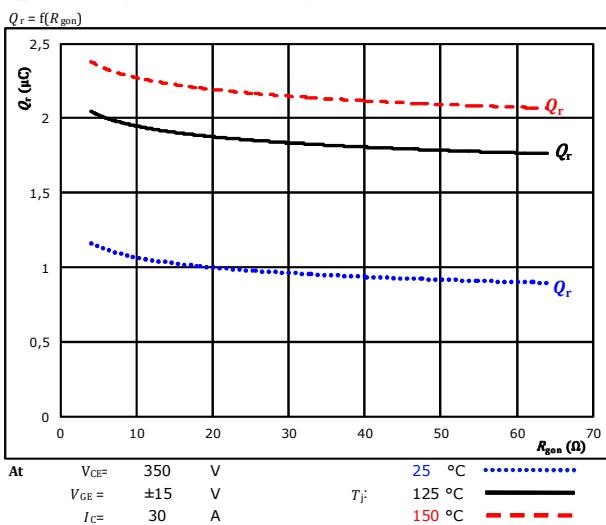


figure 11.

Typical peak reverse recovery current as a function of collector current

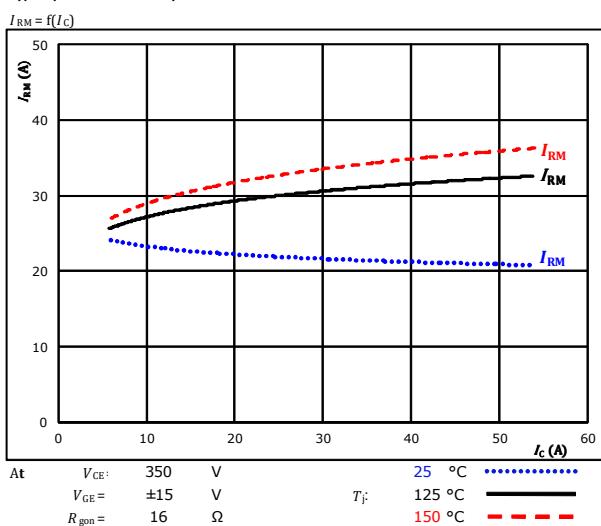
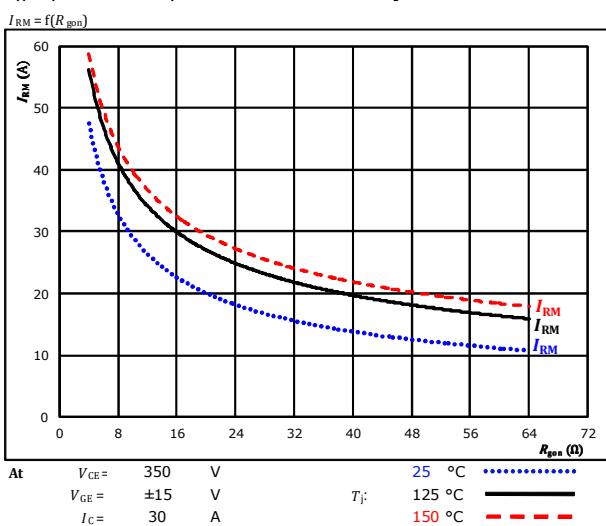


figure 12.

Typical peak reverse recovery current as a function of IGBT turn on gate resistor





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H-Bridge Switching Characteristics

figure 13.

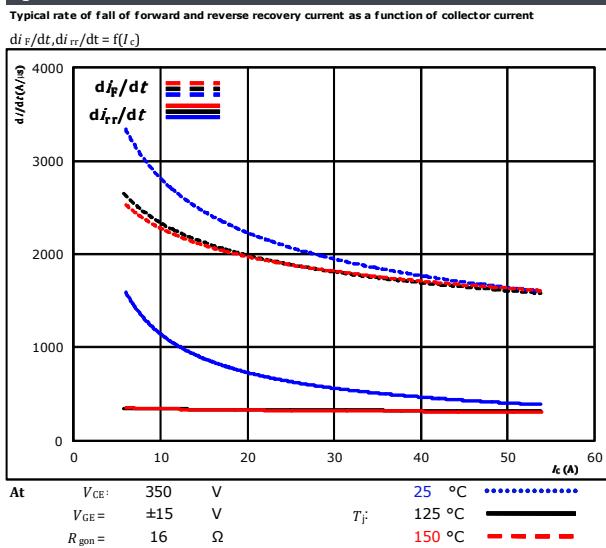


figure 14.

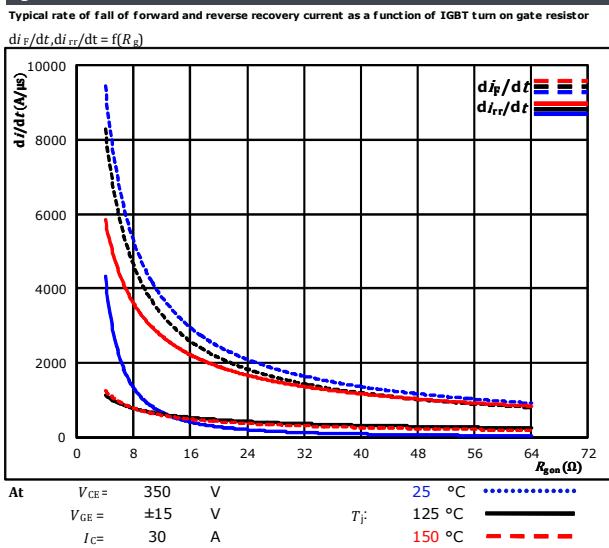
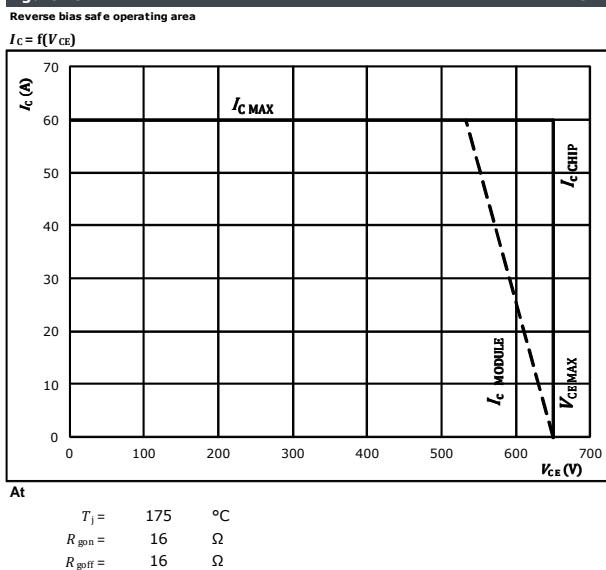


figure 15.





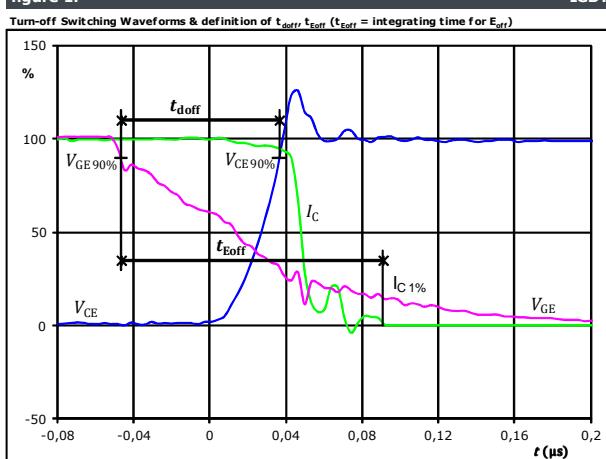
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H-Bridge Switching Definitions

General conditions

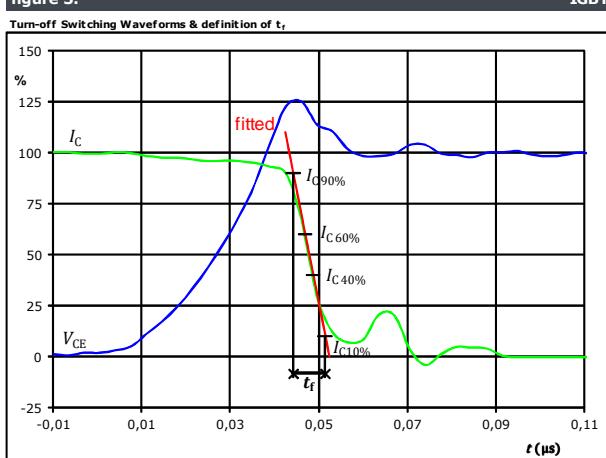
T_j	=	125 °C
R_{gon}	=	16 Ω
R_{goff}	=	16 Ω

figure 1.



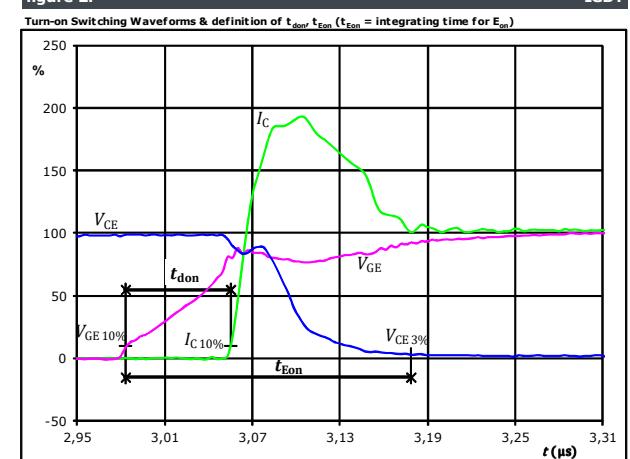
$V_{GE}(0\%) =$	-15	V
$V_{GE}(100\%) =$	15	V
$V_C(100\%) =$	350	V
$I_C(100\%) =$	30	A
$t_{doff} =$	0,083	μs
$t_{Eoff} =$	0,137	μs

figure 3.



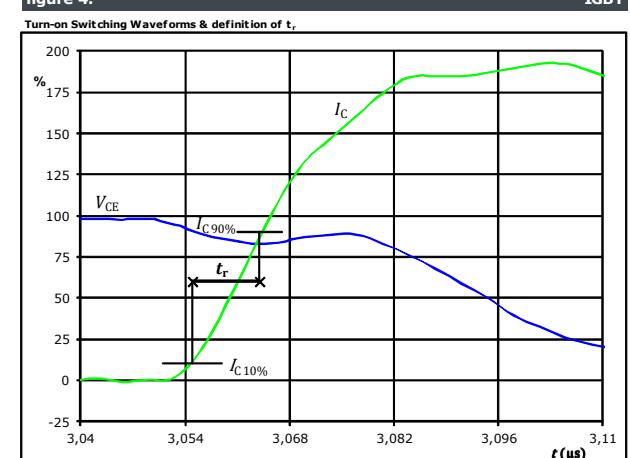
$V_C(100\%) =$	350	V
$I_C(100\%) =$	30	A
$t_f =$	0,007	μs

figure 2.



$V_{GE}(0\%) =$	-15	V
$V_{GE}(100\%) =$	15	V
$V_C(100\%) =$	350	V
$I_C(100\%) =$	30	A
$t_{don} =$	0,072	μs
$t_{Eon} =$	0,195	μs

figure 4.



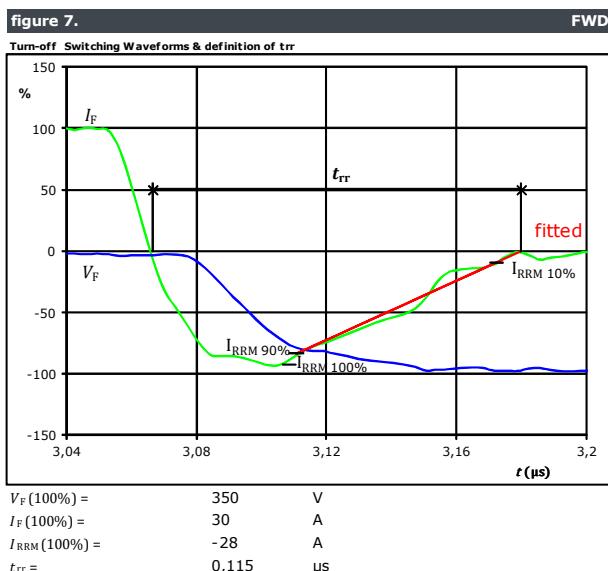
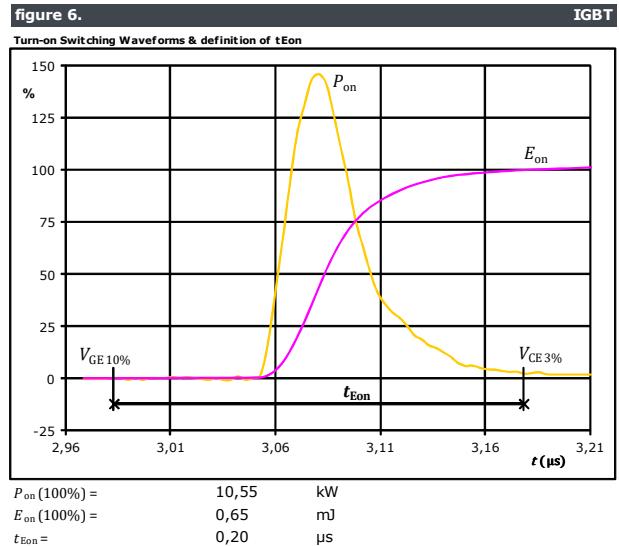
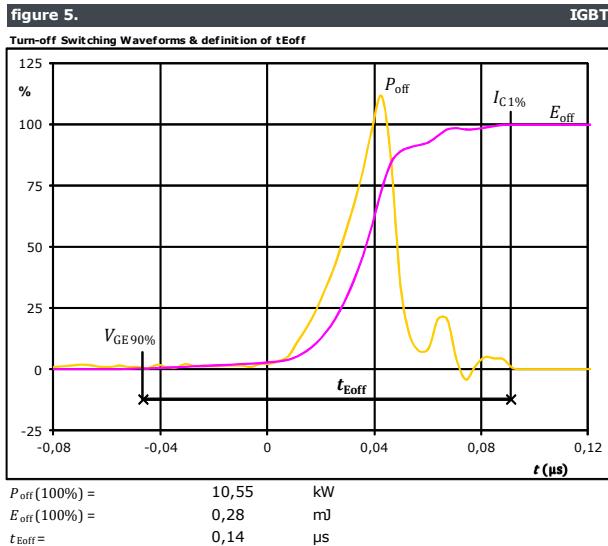
$V_C(100\%) =$	350	V
$I_C(100\%) =$	30	A
$t_r =$	0,009	μs



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H-Bridge Switching Characteristics

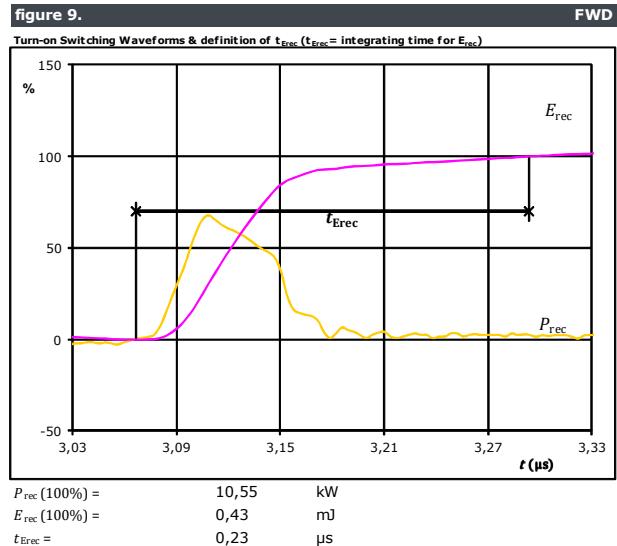
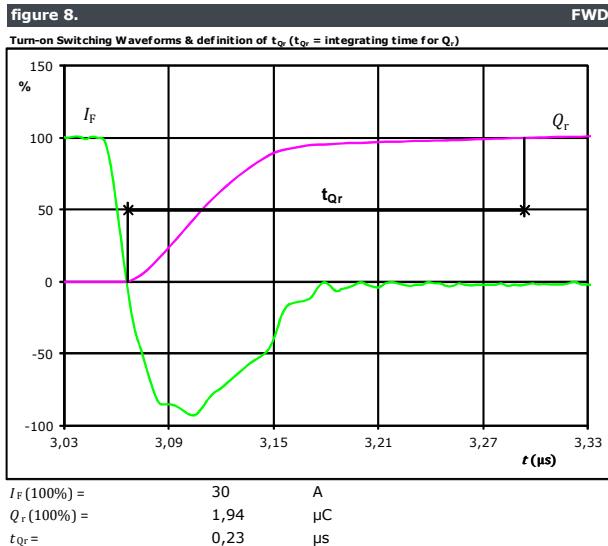




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H-Bridge Switching Characteristics





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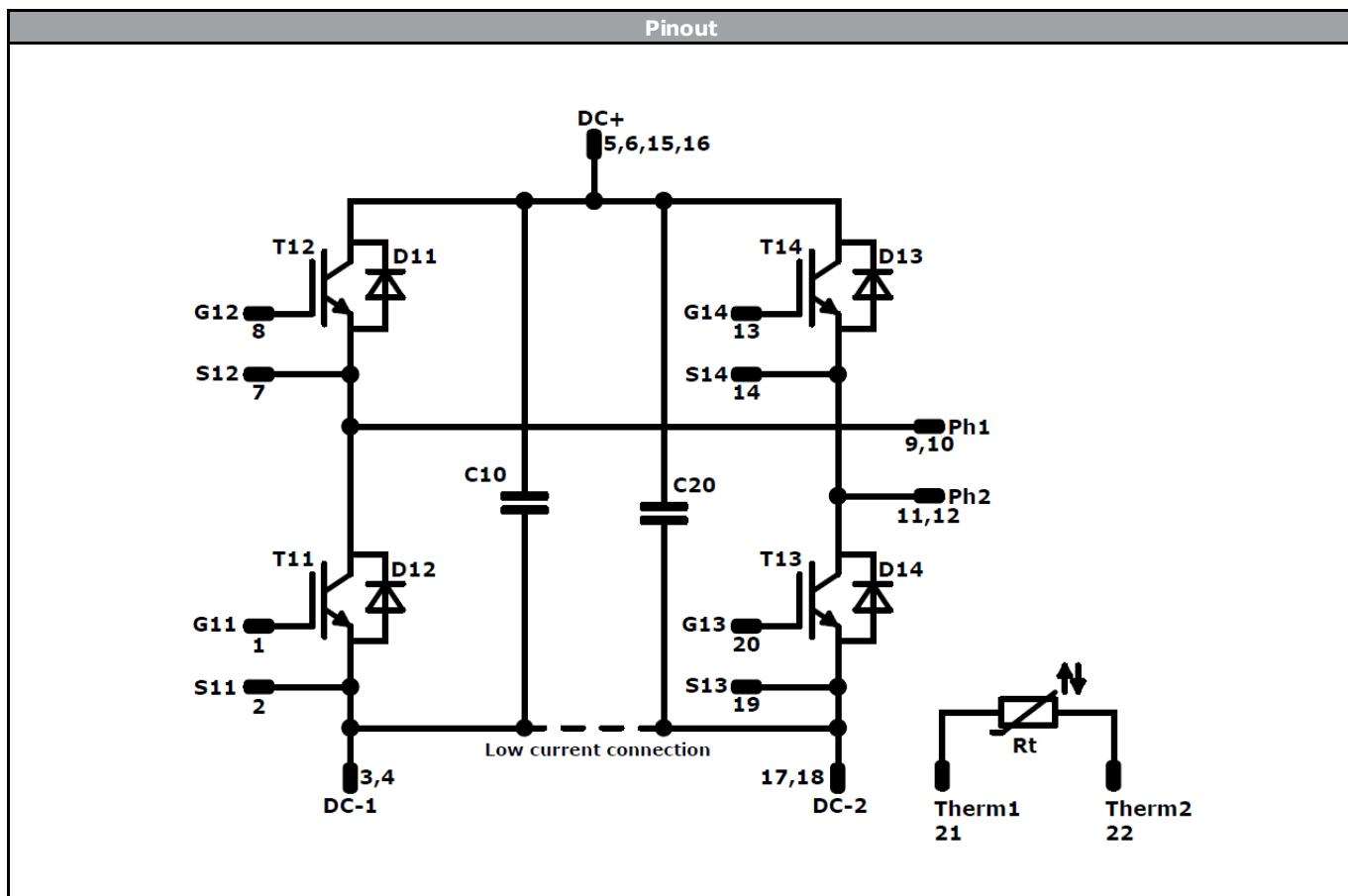
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Ordering Code & Marking							
Version				Ordering Code			
without thermal paste 12 mm housing with solder pins				10-FZ074PA030SM-L623F08			
without thermal paste 12 mm housing with press-fit pins				10-PZ074PA030SM-L623F08Y			
NN-NNNNNNNNNNNNN TTTTTTVVWWYY UL VIN LLLLL SSSS			Text	Name	Date code	UL & VIN	Lot
			Datamatrix	NN-NNNNNNNNNNNNN-TTTTTTVW	WWYY	UL VIN	LLLLL
				Type&Ver	Lot number	Serial	Date code
				TTTTTTVV	LLLLL	SSSS	WWYY
Outline							
Pin table [mm]							
Pin	X	Y	Function				
1	0	22,5	G11				
2	2,9	22,5	S11				
3	8,3	22,5	DC-1				
4	10,8	22,5	DC-1				
5	19,6	22,5	DC+				
6	22,1	22,5	DC+				
7	29,1	22,5	S12				
8	32	22,5	G12				
9	33,5	17,8	Ph1				
10	33,5	15,3	Ph1				
11	33,5	7,2	Ph2				
12	33,5	4,7	Ph2				
13	32	0	G14				
14	29,1	0	S14				
15	22,1	0	DC+				
16	19,6	0	DC+				
17	10,8	0	DC-2				
18	8,3	0	DC-2				
19	2,9	0	S13				
20	0	0	G13				
21	0	8	Therm1				
22	0	14,5	Therm2				



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Identification					
ID	Component	Voltage	Current	Function	Comment
T11-T14	IGBT	650 V	30 A	H-Bridge Switch	
D11-D14	FWD	650 V	30 A	H-Bridge Diode	
C10, C20	Capacitor	630 V		Capacitor (DC)	
Rt	NTC			Thermistor	



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Packaging instruction			
Standard packaging quantity (SPQ) 135	>SPQ	Standard	<SPQ Sample

Handling instruction			
Handling instructions for flow 0 packages see vincotech.com website.			

Package data			
Package data for flow 0 packages see vincotech.com website.			

UL recognition and file number			
This device is certified according to UL 1557 standard, UL file number E192116. For more information see vincotech.com website.			

Document No.:	Date:	Modification:	Pages
10-xZ074PA030SM-L623F08x-D2-14	18 Oct 2017		

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2. A critical component is any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.